

International **IR** Rectifier

Hyperfast Rectifier

Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature
- Lead-Free ("PbF" suffix)

20CTH03SPbF
20CTH03-1PbF

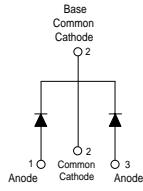
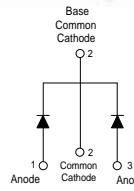
$t_{rr} = 35\text{ns max.}$
 $I_{F(AV)} = 20\text{Amp}$
 $V_R = 300\text{V}$

Description/ Applications

International Rectifier's 300V series are the state of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and Hyperfast recovery time. The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics. These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Reverse Voltage	300	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 160^\circ\text{C}$ Per Diode	10	A
Per Device	20	
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ\text{C}$	120	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	°C

Case Styles	
 20CTH03SPbF  <pre> graph TD 1[1 Anode] --- O1(()) 2[2 Common Cathode] --- O2(()) 3[3 Anode] --- O3(()) O1 --- O2 --- O3 </pre> D²PAK	 20CTH03-1PbF  <pre> graph TD 1[1 Anode] --- O1(()) 2[2 Common Cathode] --- O2(()) 3[3 Anode] --- O3(()) O1 --- O2 --- O3 </pre> TO-262

Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r	Breakdown Voltage, Blocking Voltage	300	-	-	V	$I_R = 100\mu\text{A}$
V_F	Forward Voltage	-	1.05	1.25	V	$I_F = 10\text{A}, T_J = 25^\circ\text{C}$
		-	0.85	0.95	V	$I_F = 10\text{A}, T_J = 125^\circ\text{C}$
I_R	Reverse Leakage Current	-	-	20	μA	$V_R = V_R \text{ Rated}$
		-	6	200	μA	$T_J = 125^\circ\text{C}, V_R = V_R \text{ Rated}$
C_T	Junction Capacitance	-	30	-	pF	$V_R = 300\text{V}$
L_S	Series Inductance	-	8	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_C = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
t_{rr}	Reverse Recovery Time	-	-	35	ns	$I_F = 1\text{A}, dI_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
		-	-	30		$I_F = 1\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}, V_R = 30\text{V}$
		-	31	-		$T_J = 25^\circ\text{C}$
		-	42	-		$T_J = 125^\circ\text{C}$
I_{RRM}	Peak Recovery Current	-	2.4	-	A	$T_J = 25^\circ\text{C}$
		-	5.6	-		$T_J = 125^\circ\text{C}$
Q_{rr}	Reverse Recovery Charge	-	36	-	nC	$T_J = 25^\circ\text{C}$
		-	120	-		$T_J = 125^\circ\text{C}$

Thermal - Mechanical Characteristics

Parameters			Min	Typ	Max	Units	
T_J	Max. Junction Temperature Range		- 65	-	175	$^\circ\text{C}$	
T_{Stg}	Max. Storage Temperature Range		- 65	-	175		
R_{thJC}	Thermal Resistance, Junction to Case		Per Diode	-	1.5	$^\circ\text{C/W}$	
	Weight			-	2.0	g	
				-	0.07	(oz)	
Mounting Torque			6.0	-	12	Kg-cm	
			5.0	-	10	lbf.in	
Marking Device			20CTH03S		Case style D ² Pak		
			20CTH03-1		Case style TO-262		

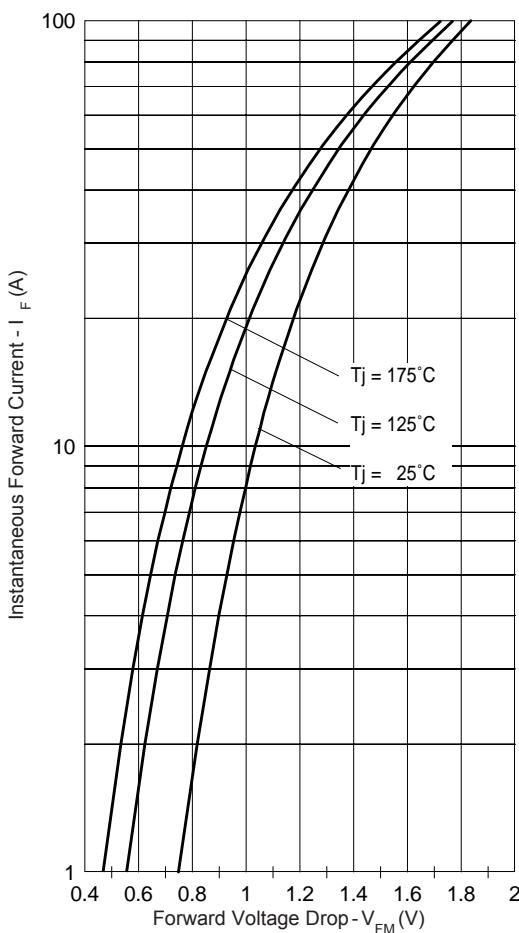


Fig. 1 - Typical Forward Voltage Drop Characteristics

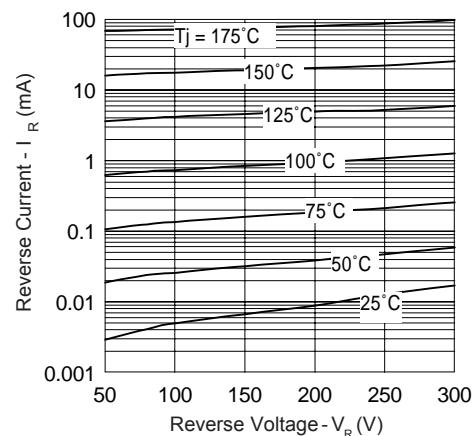


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

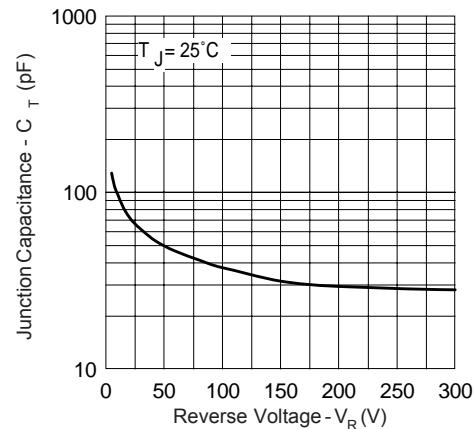


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

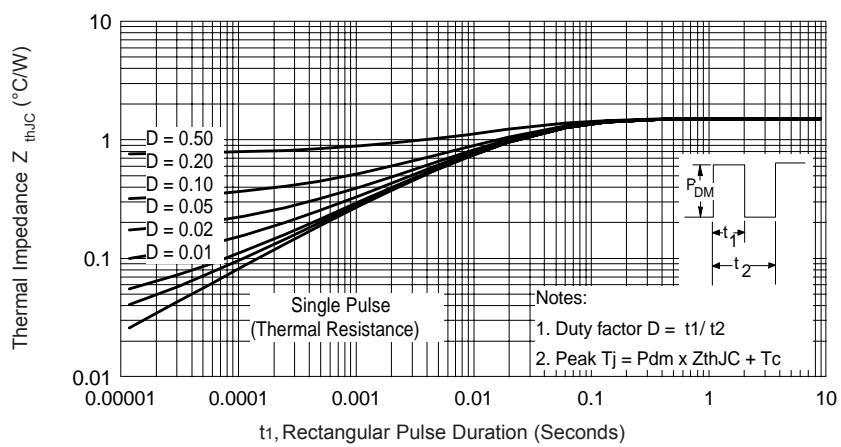


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

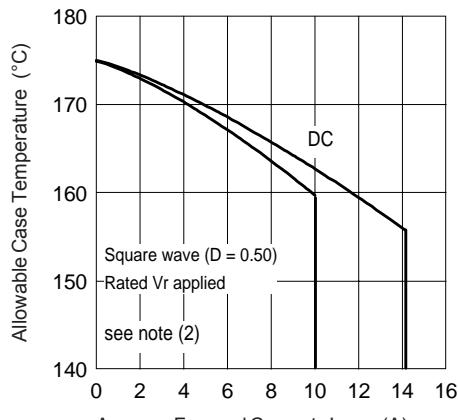


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

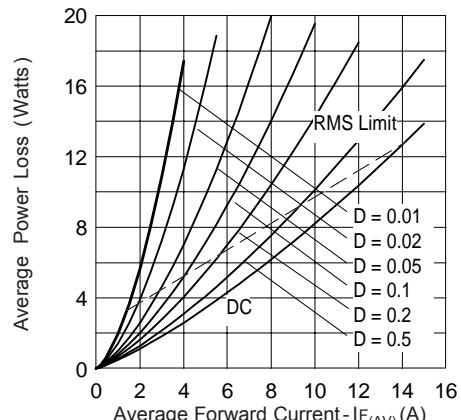


Fig. 6 - Forward Power Loss Characteristics

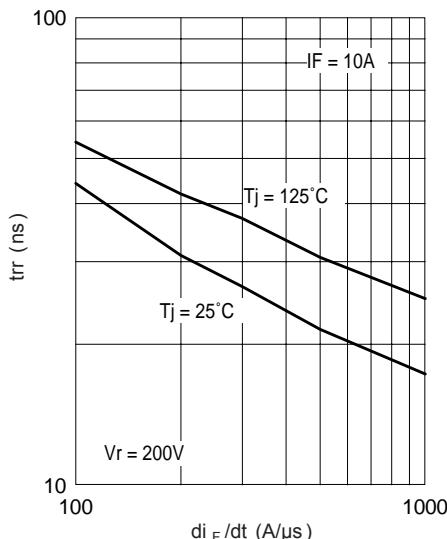


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

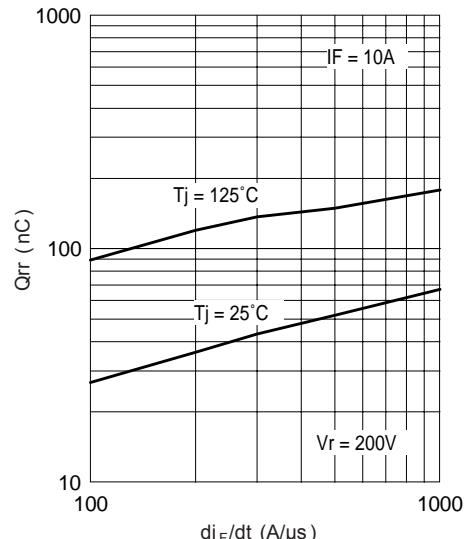


Fig. 8 - Typical Stored Charge vs. di_F/dt

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$; $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 8);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$

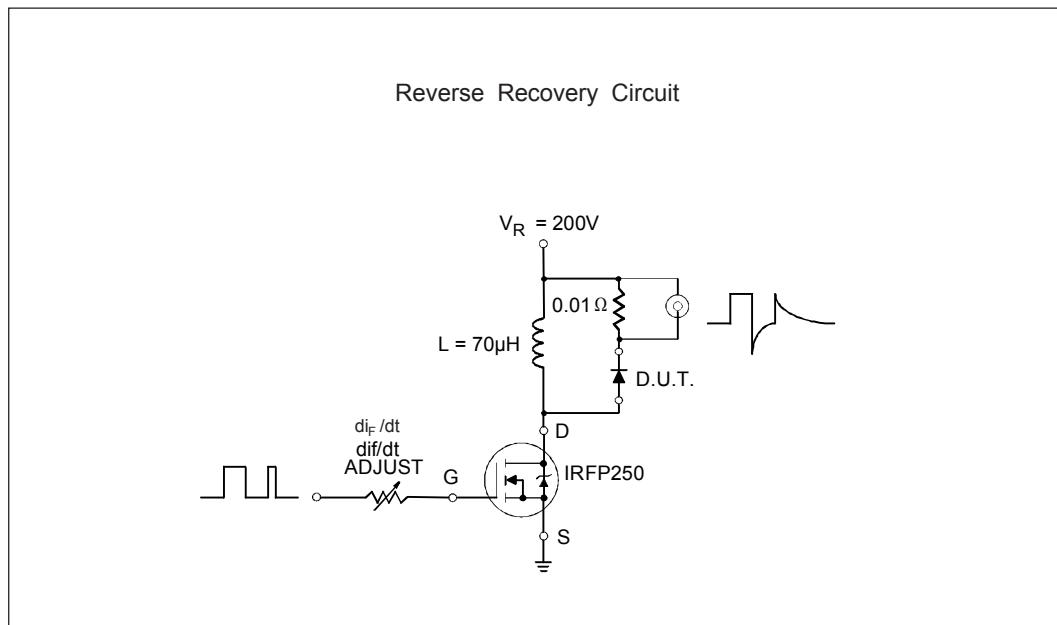


Fig. 9- Reverse Recovery Parameter Test Circuit

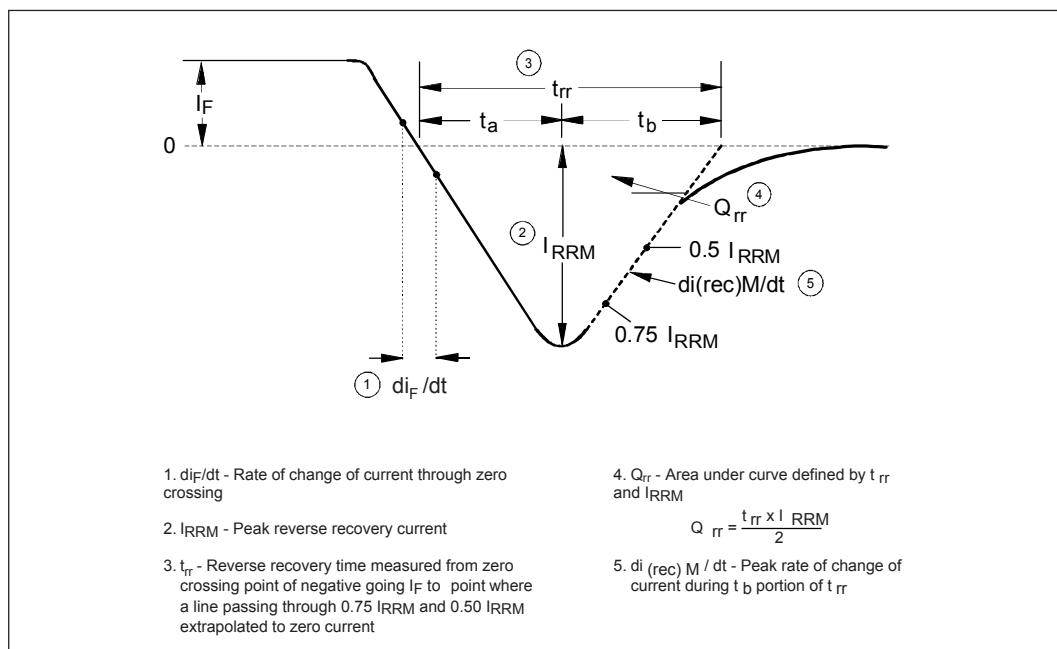
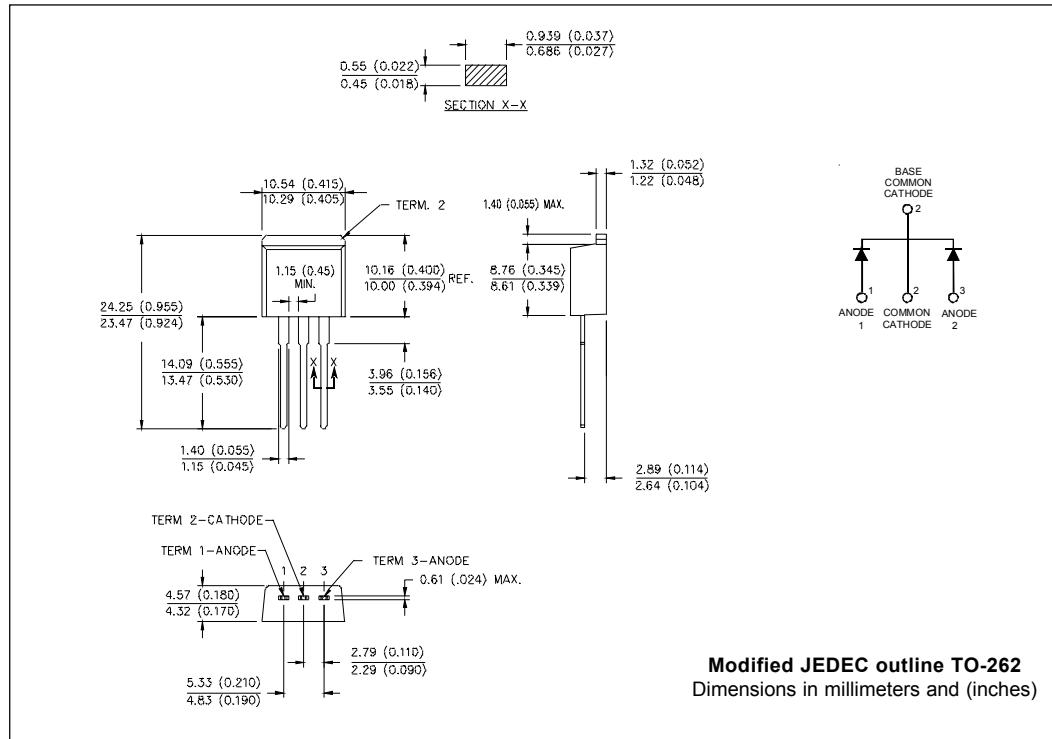
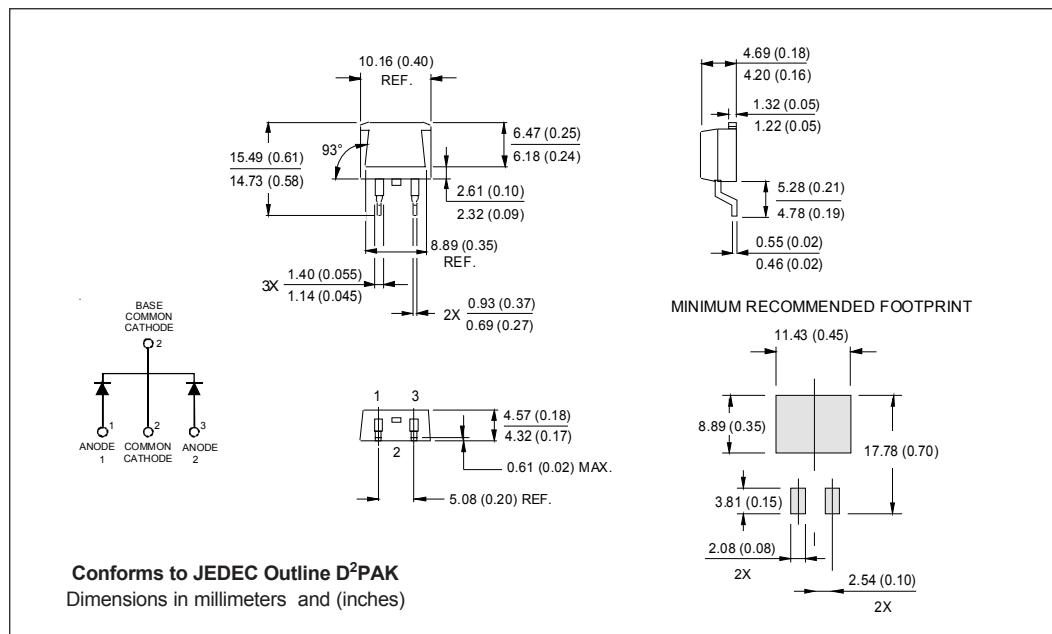


Fig. 11 - Reverse Recovery Waveform and Definitions

Outline Table

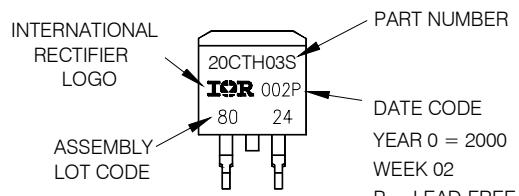


Part Marking Information

D²PAK

EXAMPLE: THIS IS A 20CTH03S
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

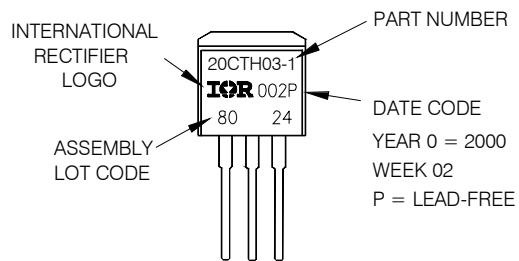
Note: "P" in assembly line
position indicates "Lead-Free"



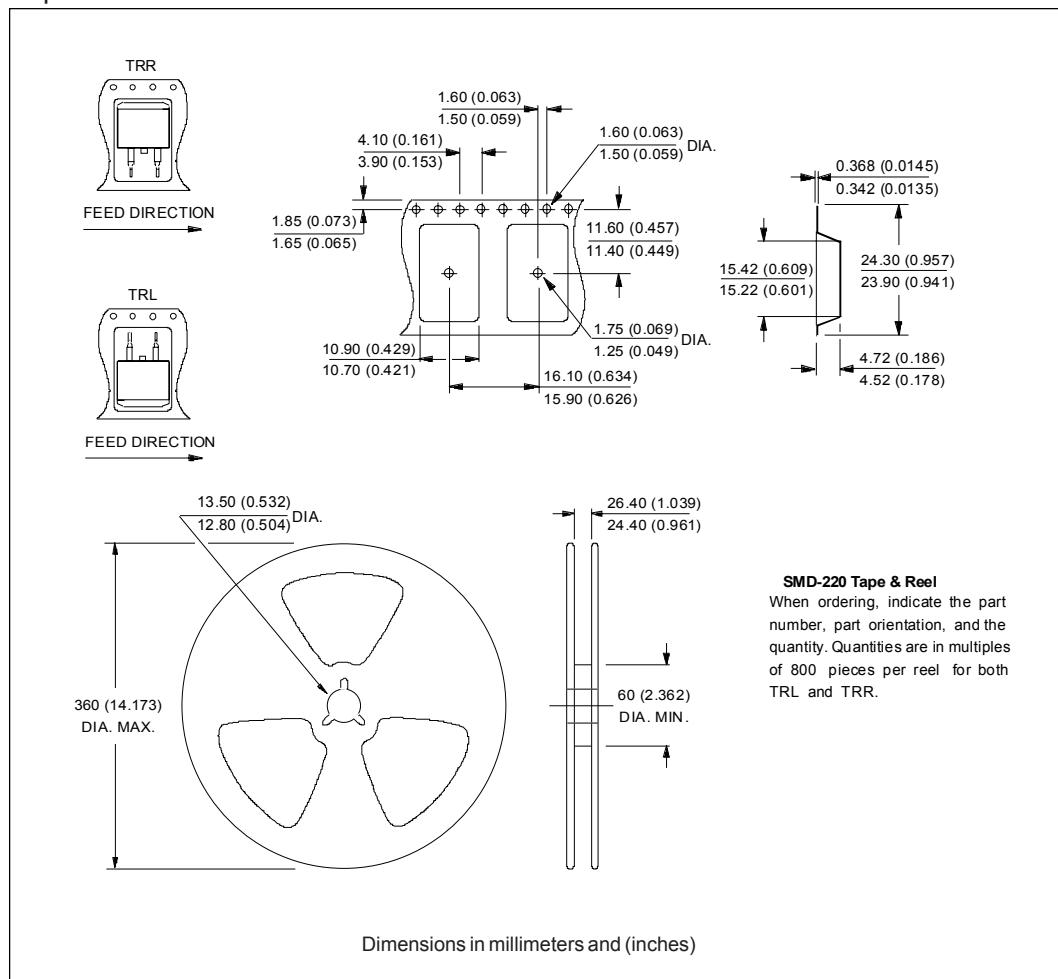
TO-262

EXAMPLE: THIS IS A 20CTH03-1
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

Note: "P" in assembly line
position indicates "Lead-Free"



Tape & Reel Information



Ordering Information Table

Device Code	20	C	T	H	03	S	TRL	PbF
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
1	- Current Rating (20A)							
2	- C = Common Cathode							
3	- T = TO-220, D ² Pak							
4	- H = Hyperfast Rectifier							
5	- Voltage Rating (03 = 300V)							
6	- • S = D ² Pak							
	- • -1 = TO-262							
7	- • none = Tube (50 pieces)							
	- • TRL = Tape & Reel (Left Oriented, for D ² PAk package)							
	- • TRR = Tape & Reel (Right Oriented, for D ² PAk package)							
8	- • none = Standard Production							
	- • PbF = Lead-Free							

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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